UNITED STATES PATENT AND TRADEMARK OFFICE
BEFORE THE PATENT TRIAL AND APPEAL BOARD
SAMSUNG ELECTRONICS CO., LTD. Petitioner
V.
DEMARAY LLC Patent Owner
Patent No. 7,544,276

PETITION FOR INTER PARTES REVIEW **OF U.S. PATENT NO. 7,544,276**



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LIST OF EXHIBITS

Ex. 1001	U.S. Patent No. 7,544,276
Ex. 1002	Declaration of Dr. Vivek Subramanian
Ex. 1003	Curriculum Vitae of Dr. Vivek Subramanian
Ex. 1004	Prosecution History of U.S. Patent No. 7,544,276
Ex. 1005	U.S. Patent No. 6,342,134 to Barber et al.
Ex. 1006	U.S. Patent No. 6,485,602 to Hirose
Ex. 1007	U.S. Patent No. 5,651,865 to Sellers
Ex. 1008	A. Belkind et al., Pulsed-DC reactive sputtering of dielectrics: Pulsing parameter effects (2000)
Ex. 1009	U.S. Patent No. 4,464,223 to Gorin
Ex. 1010	U.S. Patent No. 6,132,564 to Licata
Ex. 1011	U.S. Patent No. 5,942,089 to Sproul
Ex. 1012	U.S. Patent No. 6,352,629 to Wang
Ex. 1013	S. Gibilisco, Handbook of Radio & Wireless Technology (1999)
Ex. 1014	J. Joo, Low-temperature polysilicon deposition by ionized magnetron sputtering (2000)
Ex. 1015	B. Chapman, Glow Discharge Processes
Ex. 1016	U.S. Patent No. 4,579,618 to Celestino
Ex. 1017	International Publication No. WO 02/23588 to Quon
Ex. 1018	International Publication No. WO 01/6300 to Johnson
Ex. 1019	U.S. Patent No. 6,695,954 to Hong
Ex. 1020	U.S. Patent No. 6,153,068 to Ohmi



Ex. 1021	U.S. Patent No. 4,846,920 to Keller
Ex. 1022	RESERVED
Ex. 1023	U.S. Patent No. 5,302,882 to Miller
Ex. 1024	Pinnacle Plus+ 10KW (325-650 Vdc) Master/Slave AE Bus, DeviceNet, MDXL User, UHF Output User Manual (March 2005)
Ex. 1025	The Advanced Energy MDX Magnetron Drive, Advanced Energy Industries, Inc. (March 1993)
Ex. 1026	Pinnacle 10x6 kW DeviceNet, MDXL User 5702063-C, User Manual, (May 2000)
Ex. 1027	RESERVED
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Ex. 1030	U.S. Patent No. 6,506,686 to Masuda
Ex. 1031	K. Nam, A study on the high rate deposition of CrN films with x controlled microstructure by magnetron sputtering, Surface & Coatings Technology (2000)
Ex. 1032	D. Mattox, Handbook of Physical Vapor Deposition (PVD) Processing – Film Formation, Adhesion, Surface Preparation and Contamination Control (1998)
Ex. 1033	U.S. Patent No. 5,830,327 to Kolenkow
Ex. 1034	U.S. Patent Publication No. 2001/0041252 to Laird
Ex. 1035	M. Ruske, Properties of SiO_2 and Si_3N_4 layers deposited by MF twin magnetron sputtering using different target materials, Thin Solid Films (1999)
Ex. 1036	W. Sproul, <i>High-rate reactive DC magnetron sputtering of oxide and nitride superlattice coatings</i> (1998)
Ex. 1037	U.S. Patent Publication No. 2003/0029563 to Kaushal
Ex. 1038	U.S. Patent No. 6,627,323 to Nagaraj
Ex. 1039	RESERVED



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